



# RF Noise in SG1G2 HBT Models

Technology: SG13G2

DUT: npn13g2, npn13g2l, npn13g2v

Fischer, Gerhard

December 2018



innovations  
for high  
performance  

---

microelectronics

Member of

Leibniz  
Leibniz Association

# Overview

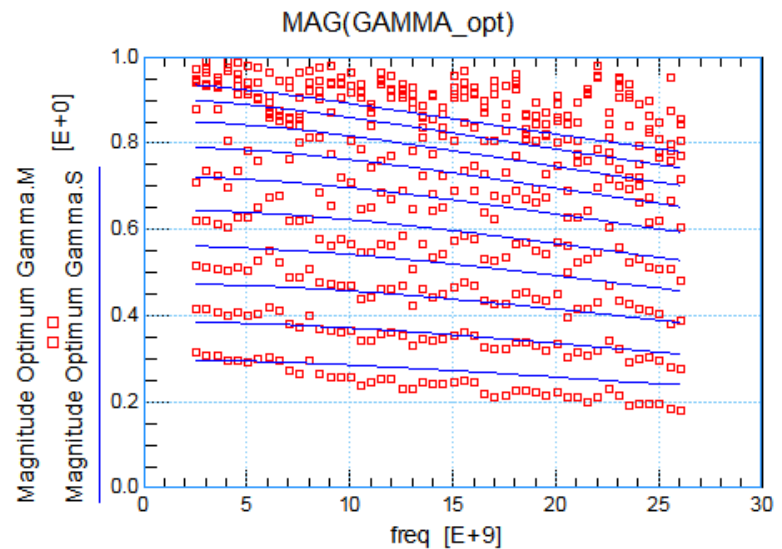
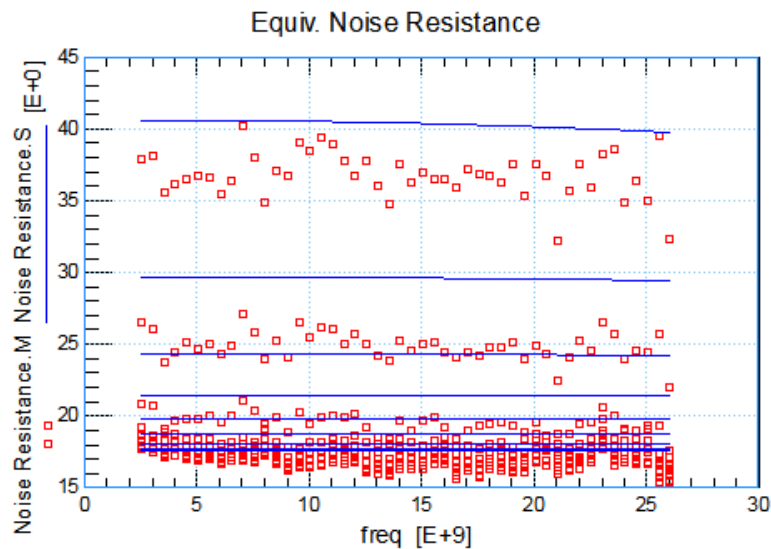
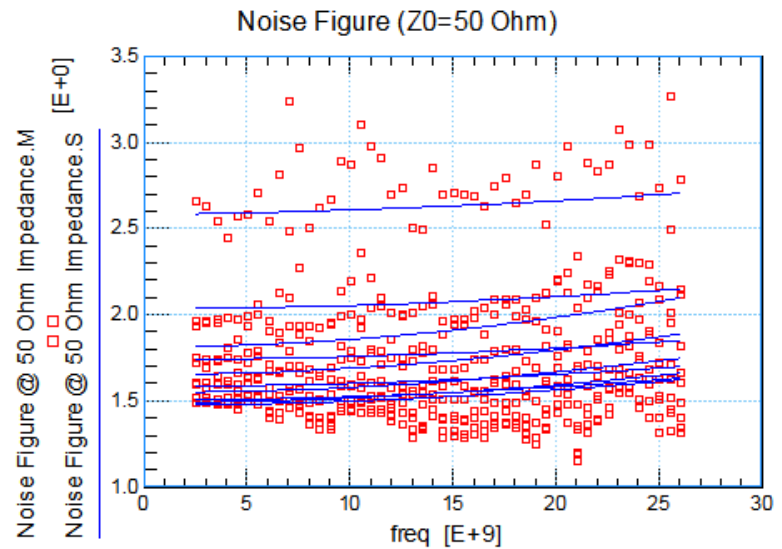
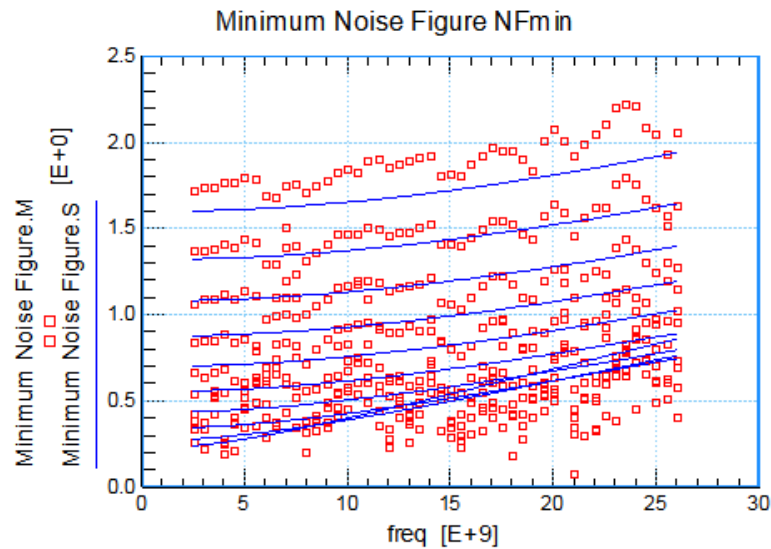
---

- RF noise measurements have been performed on all HBT types and compared to simulations with VBIC and HICUM

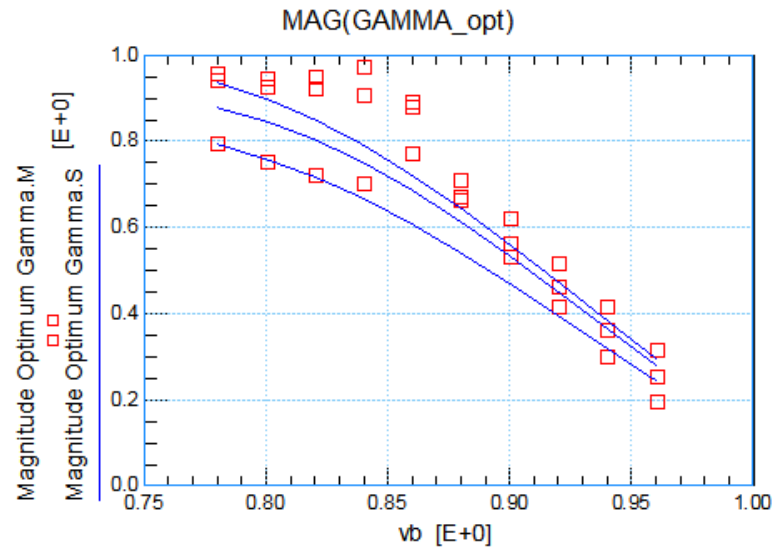
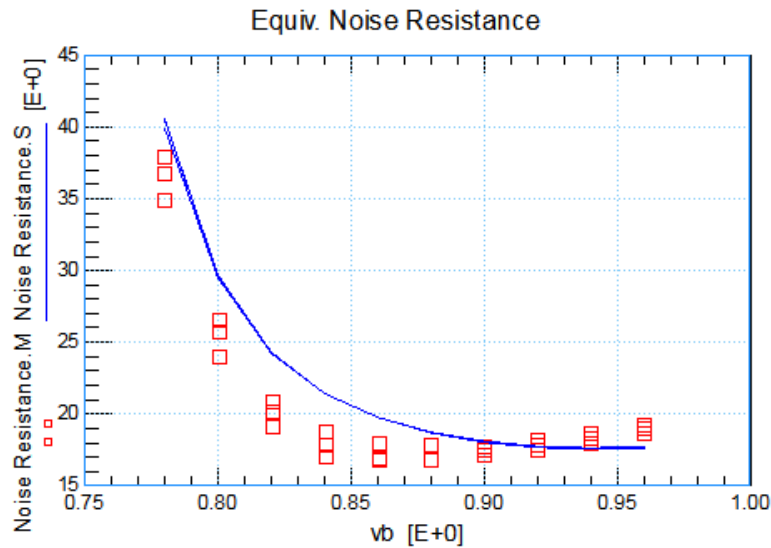
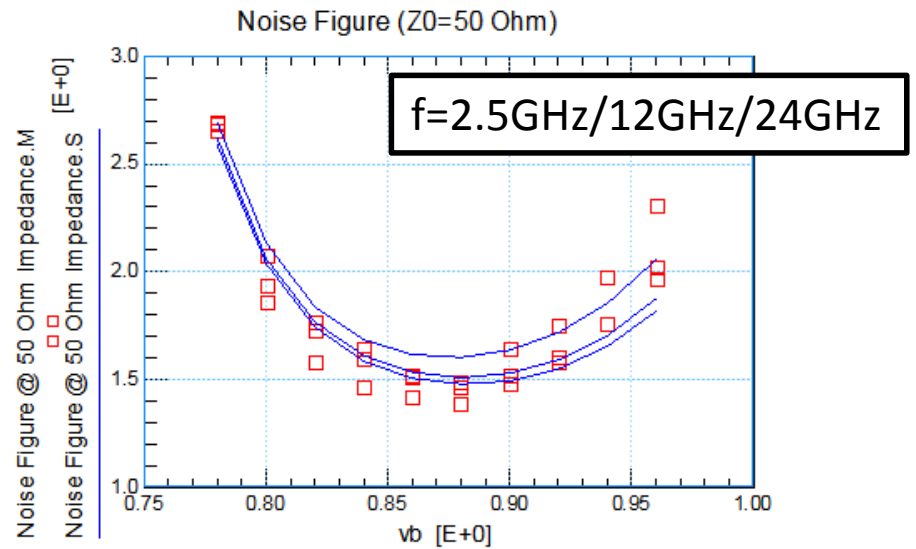
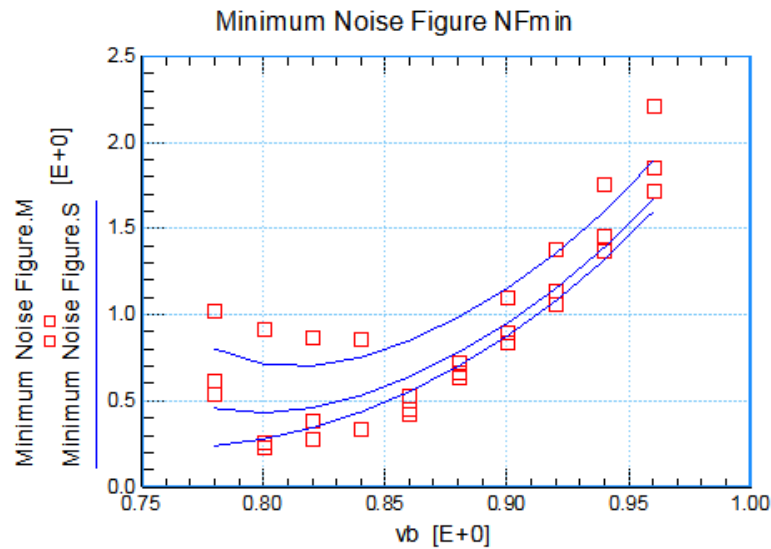
## Summary:

- Noise measurements performed on current qualification wafer
  - Operating points:  $V_{BE}=0.78...0.96V$  (g2, g2I),  $V_{CB}=0.25V$ ,  $f=2.5GHz...26GHz$
  - Operating points:  $V_{BE}=0.75...0.84V$  (g2v),  $V_{CB}=1.0V$ ,  $f=2.5GHz...26GHz$

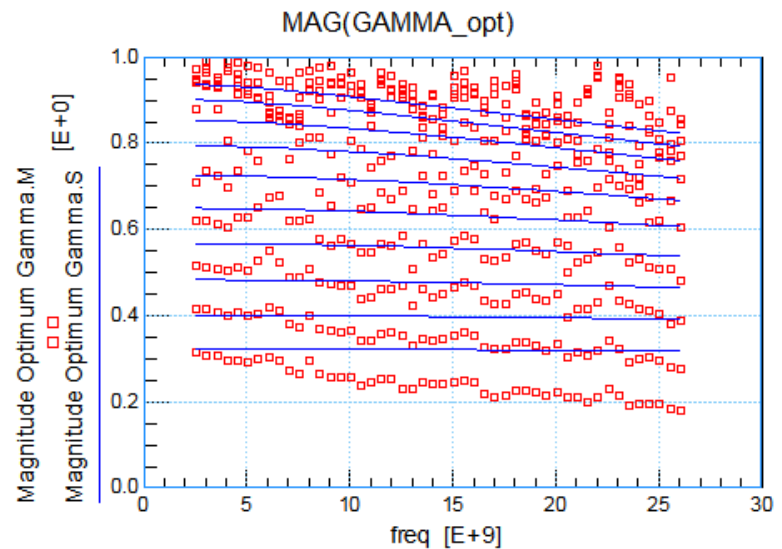
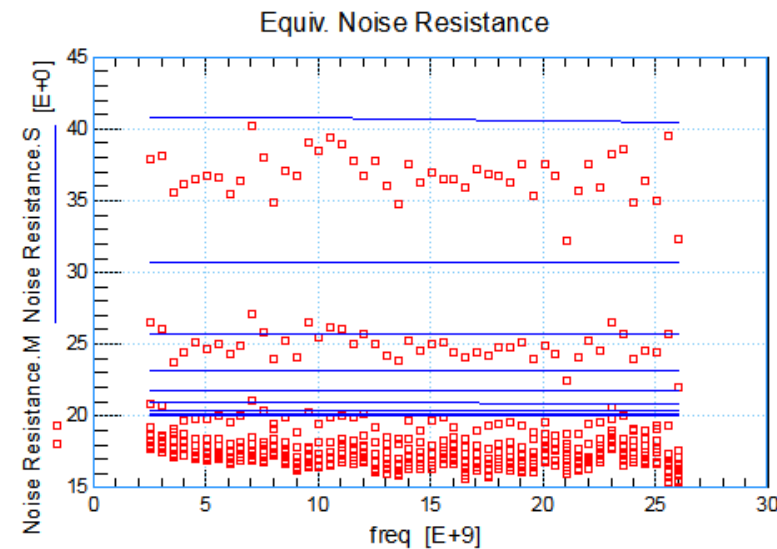
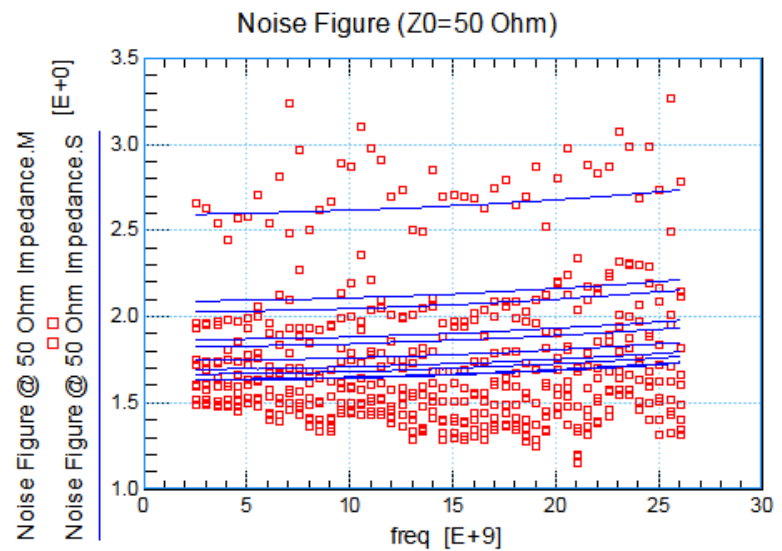
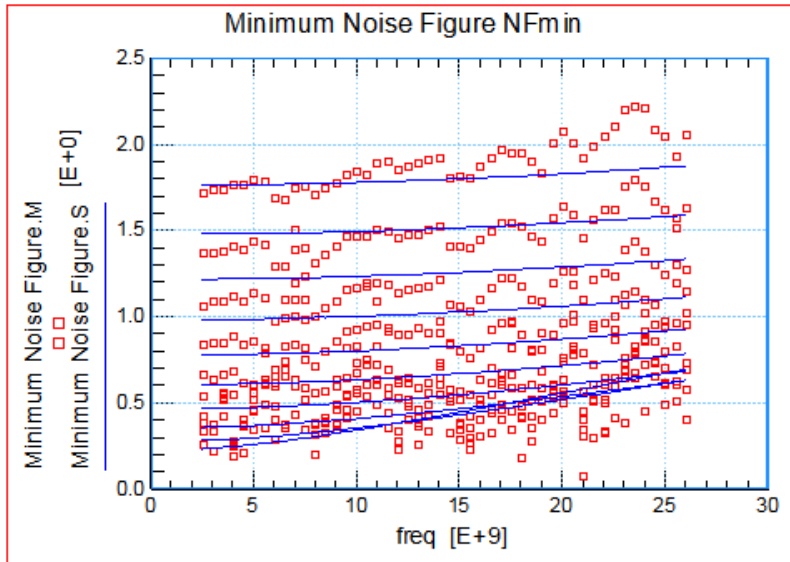
# DUT: npn13g2 Nx=8 VBIC - RF noise as function of frequency



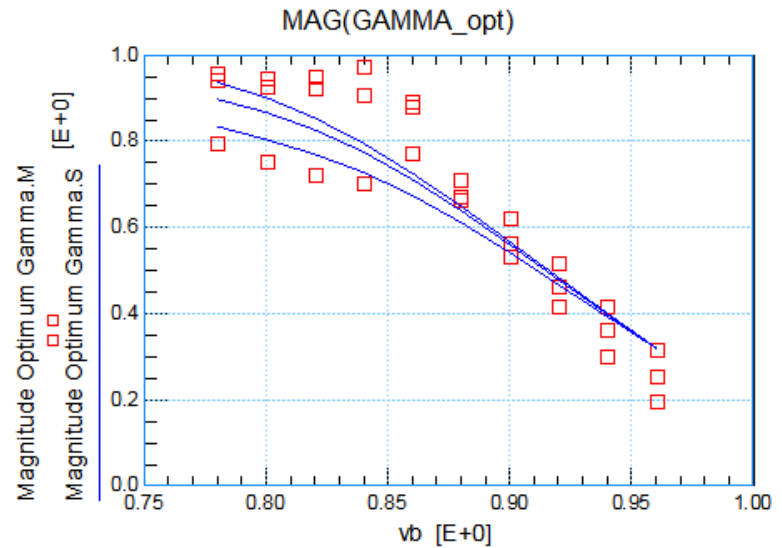
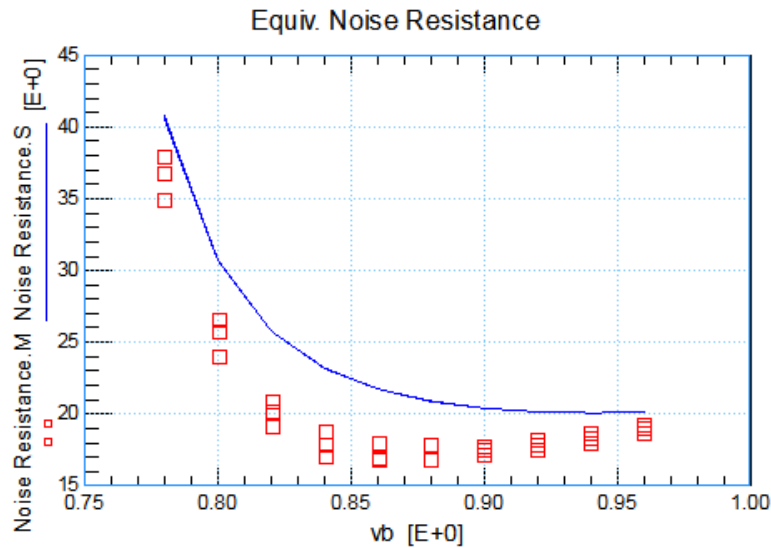
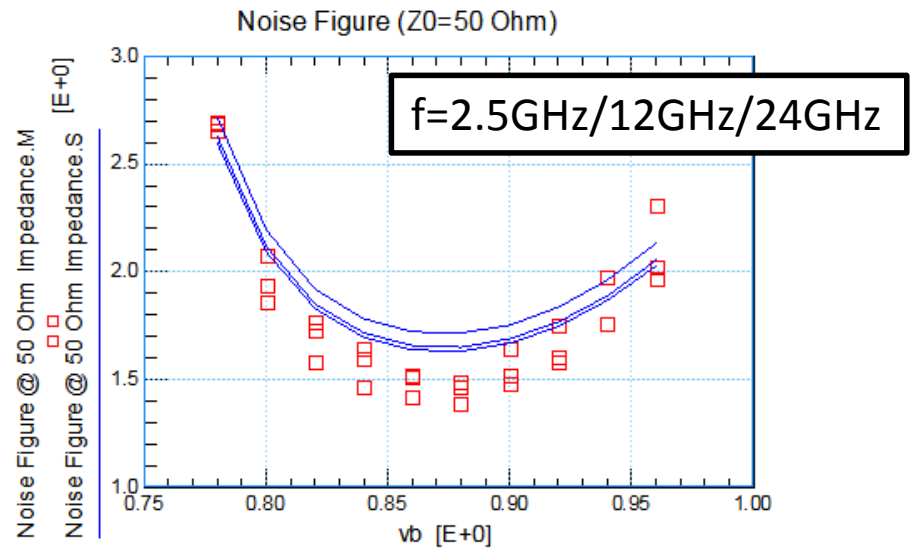
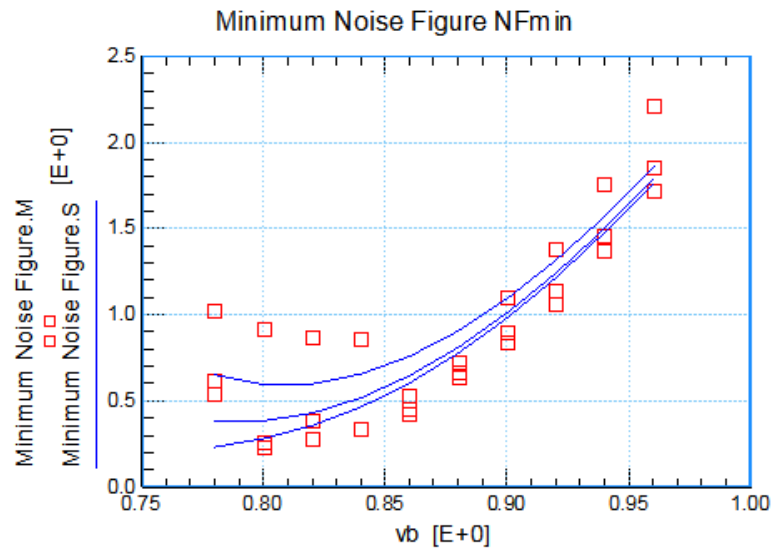
# DUT: npn13g2 Nx=8 VBIC - RF noise as function of $V_{BE}$



# DUT: npn13g2 Nx=8 HICUM - RF noise as function of frequency

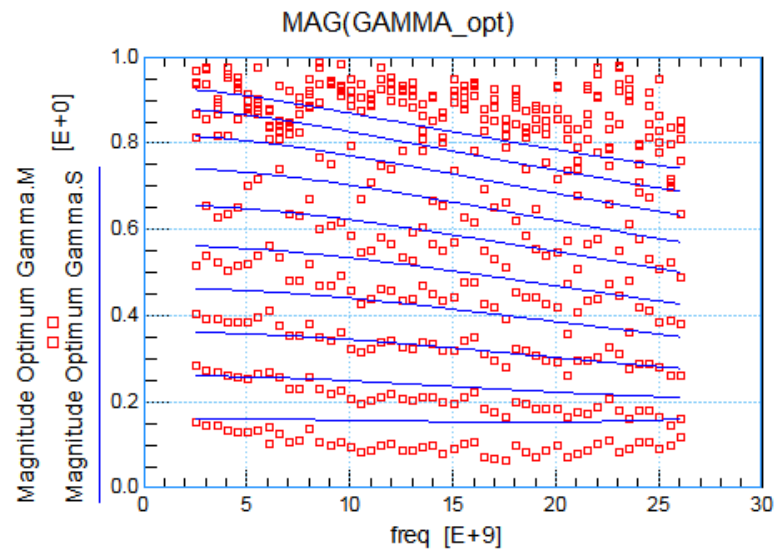
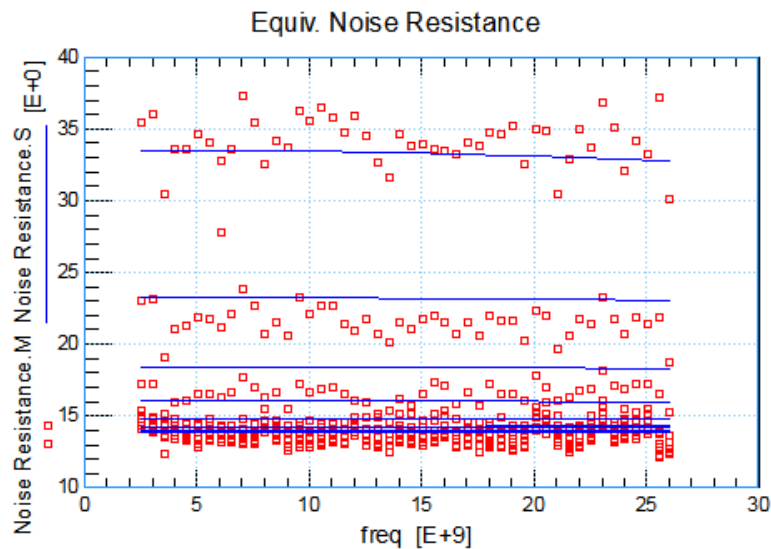
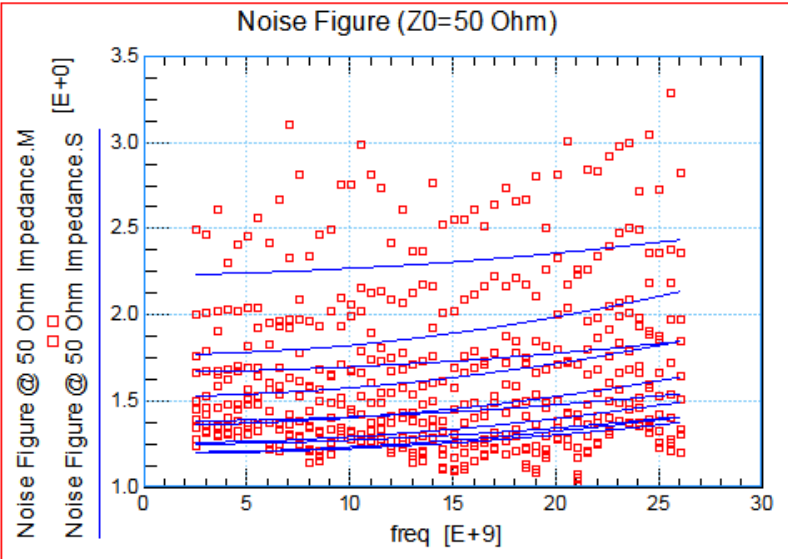
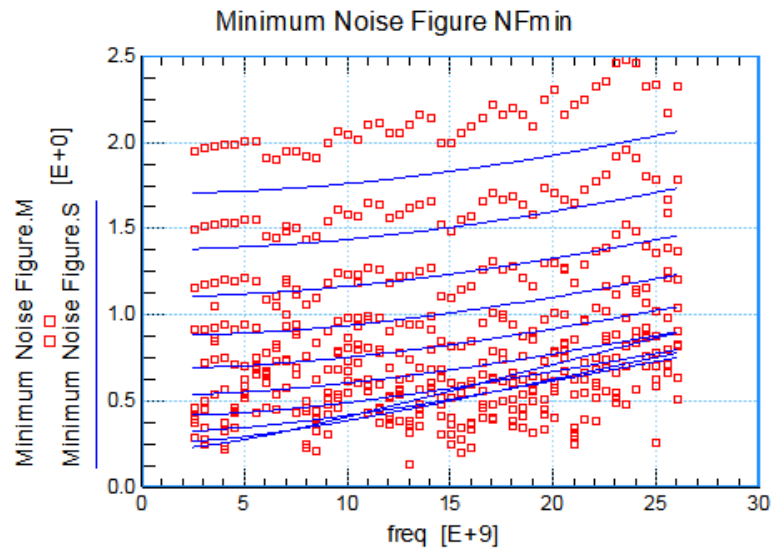


# DUT: npn13g2 Nx=8 HICUM - RF noise as function of $V_{BE}$

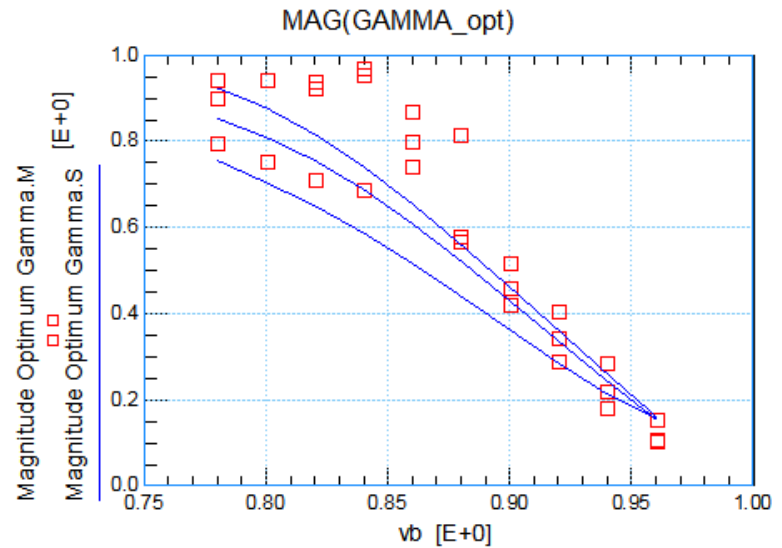
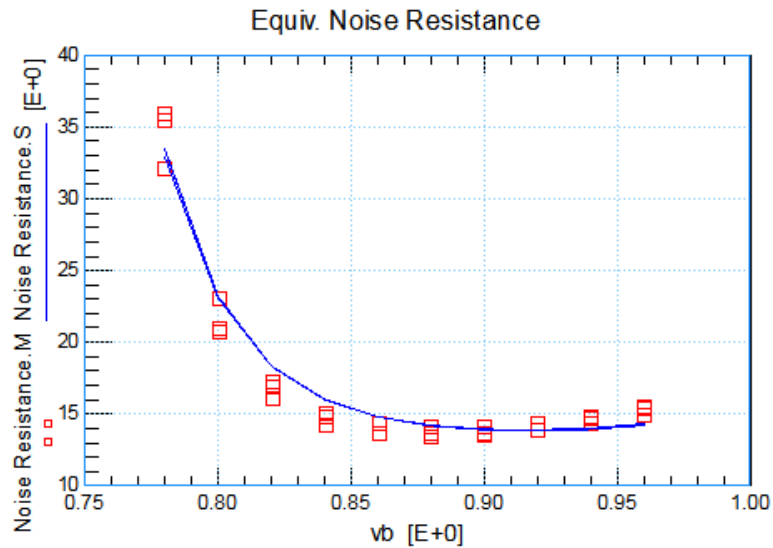
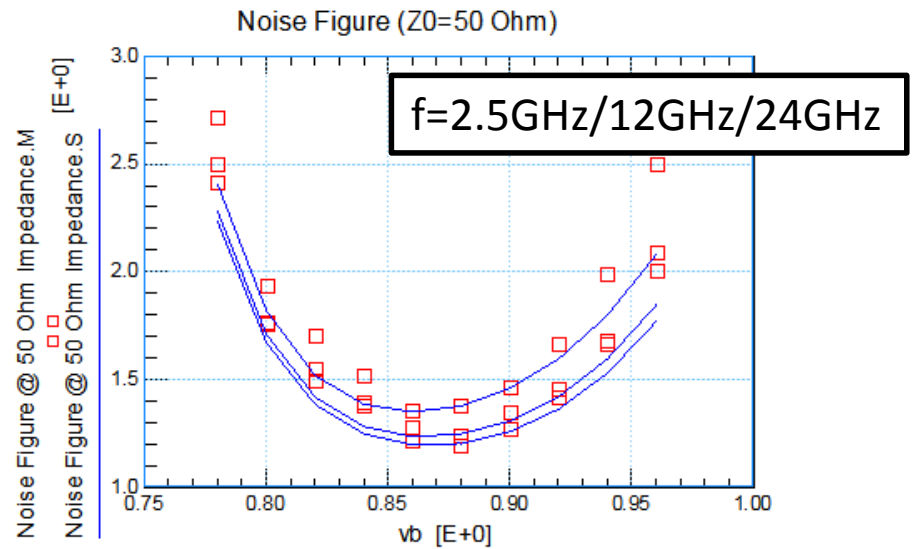
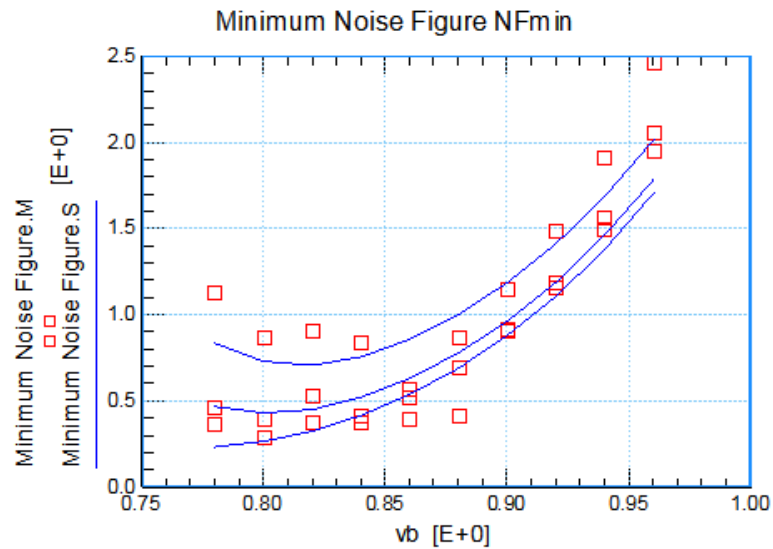




# DUT: npn13g2l Nx=4 EI=2.5 VBIC - RF noise as function of frequency

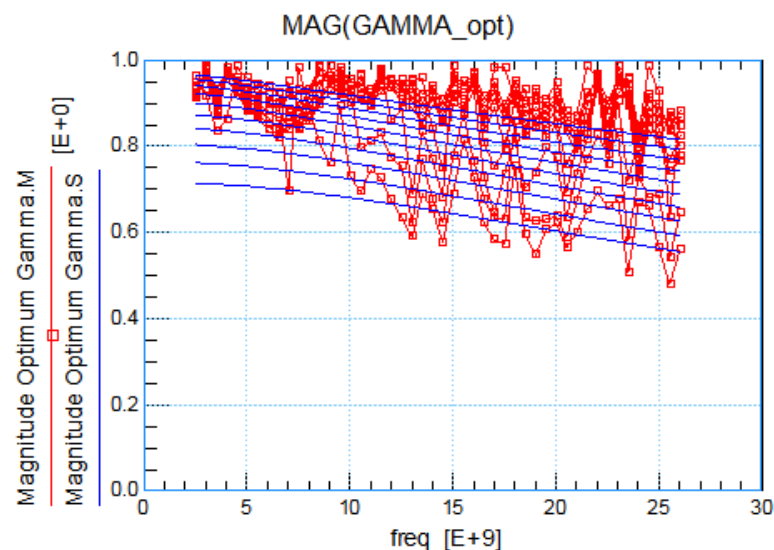
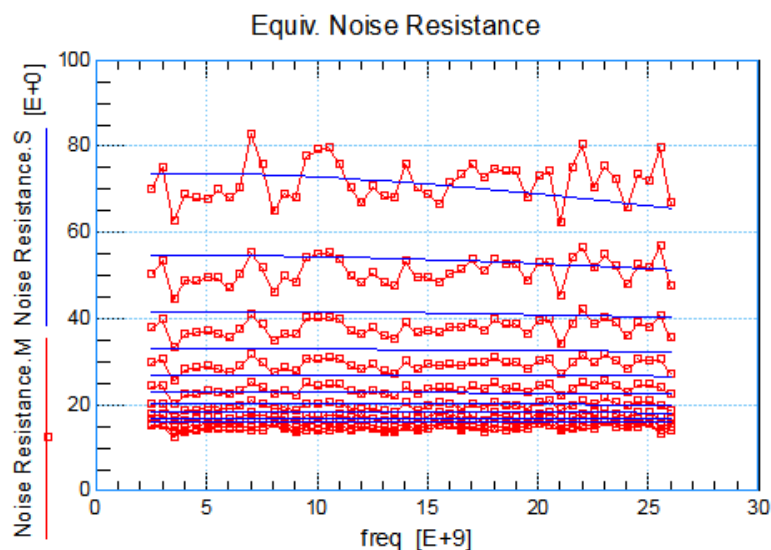
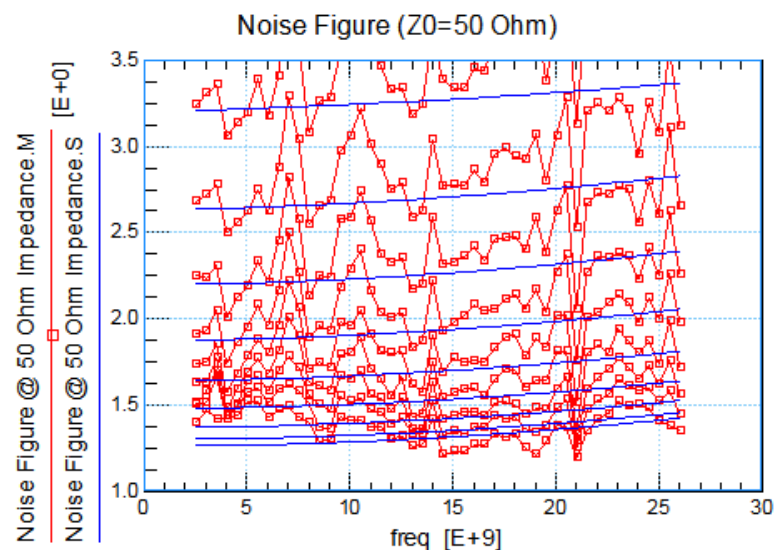
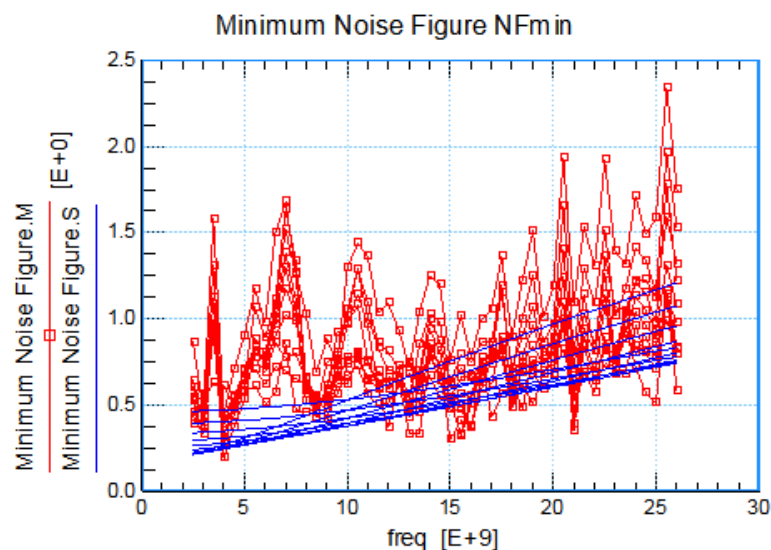


# DUT: npn13g2l Nx=4 EI=2.5 VBIC - RF noise as function of $V_{BE}$





# DUT: npn13g2v Nx=4 El=2.5 VBIC - RF noise as function of frequency



# DUT: npn13g2v Nx=4 El=2.5 VBIC - RF noise as function of $V_{BE}$

